TOSHIBA Transistor Silicon NPN Triple Diffused Mesa Type

# 2SC5355

High Voltage Switching Applications Switching Regulator Applications DC-DC Converter Applications

- Excellent switching times:  $t_r = 0.5 \mu s$  (max),  $t_f = 0.3 \mu s$  (max)
- High collector breakdown voltage:  $V_{CEO} = 400 \text{ V}$
- High DC current gain: hFE = 20 (min)

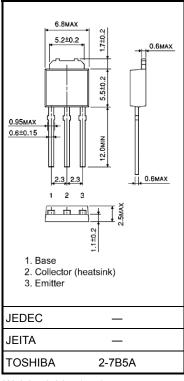
### Absolute Maximum Ratings (Ta = 25°C)

Characteristics		Symbol	Rating	Unit	
Collector-base voltage		V <sub>CBO</sub>	600	V	
Collector-emitter voltage		V <sub>CEO</sub>	400	V	
Emitter-base voltage		V <sub>EBO</sub>	7	V	
Collector current	DC	I <sub>C</sub>	5	А	
	Pulse	I <sub>CP</sub>	7		
Base current		lΒ	1	Α	
Collector power dissipation	Ta = 25°C	P <sub>C</sub>	1.5	W	
	Tc = 25°C	FC	25		
Junction temperature		Tj	150	°C	
Storage temperature range		T <sub>stg</sub>	-55~150	°C	

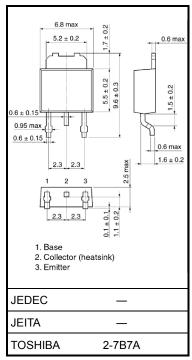
Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Unit: mm



Weight: 0.36 g (typ.)

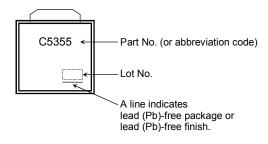


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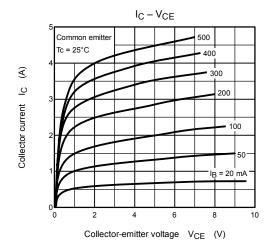
## Electrical Characteristics (Ta = 25°C)

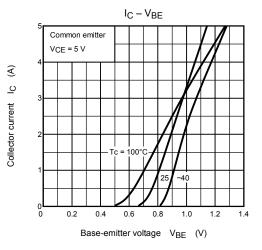
Chara	acteristics	Symbol	Test Condition		Тур.	Max	Unit
Collector cut-off of	ellector cut-off current $I_{CBO}$ $V_{CB} = 480 \text{ V}, I_{E} = 0$		_	_	100	μΑ	
Emitter cut-off cu	rrent	I <sub>EBO</sub> V <sub>EB</sub> = 7 V, I <sub>C</sub> = 0		_	_	10	μΑ
Collector-base br	ector-base breakdown voltage $V_{(BR) CBO}$ $I_C = 1 mA, I_E = 0$		600	_	_	V	
Collector-emitter	ector-emitter breakdown voltage $V_{(BR)CEO}$ $I_C = 10 \text{ mA}, I_B = 0$		400	_	_	V	
DC current gain		h <sub>FE (1)</sub>	V <sub>CE</sub> = 5 V, I <sub>C</sub> = 1 mA	12	_	_	
		h <sub>FE (2)</sub>	V <sub>CE</sub> = 5 V, I <sub>C</sub> = 0.5 A	20	_	65	
Collector-emitter	collector-emitter saturation voltage V <sub>CE (sat)</sub> I <sub>C</sub> = 2 A, I <sub>B</sub> = 0.25 A		_	_	1.0	V	
Base-emitter saturation voltage		V <sub>BE (sat)</sub>	I <sub>C</sub> = 2 A, I <sub>B</sub> = 0.25 A	_	_	1.3	V
Switching time S	Rise time	t <sub>r</sub>	20 μs IB1 OUTPUT  INPUT O W IB2  VCC ≈ 200 V	_	_	0.5	
	Storage time	t <sub>stg</sub>		_	_	2.0	μs
	Fall time	t <sub>f</sub>	$I_{B1} = 0.25 \text{ A}, I_{B2} = -0.5 \text{ A}$ DUTY CYCLE $\leq 1\%$	-	_	0.3	

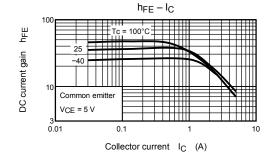
### Marking

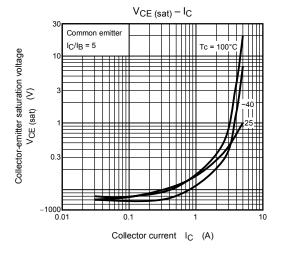


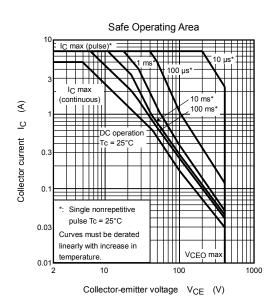
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